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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: RUECKES, et al.

Application No.: 10/776,573

Filed: February 11, 2004

For: Nanotube Films and Articles

Group Art Unit: 1775

Examiner: To Be Assigned

Attorney Docket No.: 112020.129 US3 NAN-6

CERTIFICATE OF MAILING (37 C.F.R. § 1.8 a)

I hereby certify that this correspondence is being deposited with the United States Postal Service under 37 CFR 1.8a and is addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on November 24, 2004.

By: Tina M. Dougal  
Tina M. Dougal

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §§ 1.56 and 1.97-98, and M.P.E.P. §609, Applicants hereby enclose Forms PTO-1449 that includes publications that have previously been cited in a prior patent application Serial No. 10/128,118 filed April 23, 2002, now U.S. Patent No. 6,706,402 issued March 16, 2004, from which the above application claims priority under 35 U.S.C. §120. With the exception of the following list of publications identified below, pursuant to 37 C.F.R. § 1.98(d), no further copies of the previously cited art are enclosed.

New U.S. Patents/Publications Not Previously Listed  
(Copies not required and not enclosed herewith)

US-2003/0124837
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A1	Winslow, Troy. "Advanced+ Boot Block World's First 0.18-Micron Flash Memory." Flash Products Group. April 17, 2000.
A2	"Double Sided 4Mb SRAM Coupled Cap PBGA Card Assembly Guide." International Business Machines Corp. (IBM), 1998.
A248	Dai, Hongjie. "Controlled Chemical Routes to Nanotube Architectures, Physics, and Devices." <i>The Journal of Physical Chemistry B</i> (1999); 103: 11246-11255.
A249	Colomer, J.-F., et al., "Characterization of Single-Walled Carbon Nanotubes Produced by CCVD Method." <i>Chemical Physics Letters</i> (2001); 345, 11-17.
A251	Cassell, A., et al., "Large Scale Synthesis of Single-Walled Carbon Nanotubes." <i>The Journal of Physical Chemistry B</i> (1999); Vol. 103, No. 22: 6484-6492.
A258	Homma, Y., et al., "Growth of Suspended Carbon Nanotube Networks on 100nm-Scale Silicon Pillars." <i>Applied Physics Letters</i> . (2002); Vol. 81 No. 12, 2261-2263.
A260	Kong, J., et al., "Syntheses of Individual Single-Walled carbon Nanotubes on Patterned Wafers." <i>Nature</i> (1998); 395: 878-881.
A263	Peigney, A., et al., "A Study of the Formation of Single-and-Double-Walled carbon Nanotubes by a CVD Method." <i>The Journal of Physical Chemistry B</i> (2001); 105: 9699-9710.
A264	Franklin, N., et al., "Integration of Suspended Carbon Nanotube Arrays into

	Electronic Devices and Electrochemical Systems." <i>Applied Physics Letters</i> (2002); Vol. 81 No. 5, 913-905.
A267	Reuckes, T., et al., "Carbon Nanotube-Based Nonvolatile Random Access Memory for Molecular Computing." <i>Science</i> , vol. 289, 94-97, July 7, 2000
A269	Soh, et al., "Integrated Nanotube Circuits: controlled growth and ohmic contacting of single-walled carbon nanotubes", <i>Applied Physics Letters</i> , August 2, 1999, Vol. 75, No. 5, 627-629
A276	Snow, E.S. et al., "Random Networks of Carbon Nanotubes as an Electronic Material." <i>Applied Physics Letters</i> , March 31, 2003, Vol. 82, No. 13, 2145-2147.
A277	Bernholc et al., "Mechanical and Electrical Properties of Nanotubes", <i>Annu. Rev. Mater. Res.</i> , 32 (2002) 347.

**Enclosed Foreign Patents/Applications**

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EP 1061040 A1

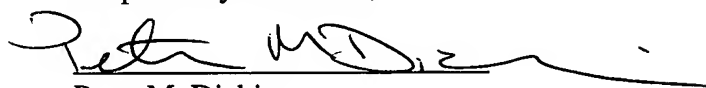
EP 1061043 A1

It is respectfully requested that the information above be expressly considered and that the publications be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

As this paper is being filed prior to the issuance of a first Office Action on the merits, and pursuant to 37 C.F.R. § 1.97(b)(3), no fee is believed to be due. In the event a fee is due, the Commissioner is authorized to charge any fee deficiency or credit any overpayment to Deposit Account No. 08-0219.

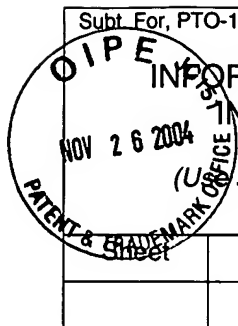
Dated: November 24, 2004

Respectfully submitted,



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Subt. For, PTO-1449		Docket Number 112020.129US3 NAN-6	Application Number 10/776,573
		Applicant SEGAL, Brent M., et al.	
		Filing Date February 11, 2004	Group Art Unit 1775
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U.S. Patent Documents				
Examiner Initial	Document No.	Publication Date mm-dd-yyyy	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
	US-5,346,683	09/13/1994	Green et al.	
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				Applicant <b>SEGAL, Brent M., et al.</b>			
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Subt. For, PTO-1449  <b>INFORMATION DISCLOSURE IN AN APPLICATION</b>  <i>(Use several sheets if necessary)</i>				Docket Number <b>112020.129US3 NAN-6</b>		Application Number <b>10/776,573</b>	
				Applicant <b>SEGAL, Brent M., et al.</b>			
				Filing Date <b>February 11, 2004</b>		Group Art Unit <b>1775</b>	
Sheet	39	OF	40				

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)		
Examiner Initial	Cite	
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Sheet	40	OF	40				

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)		
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	A272	Chattopadhyay, et al., "Metal-Assisted Organization of Shortened Carbon Nanotubes in Monolayer and Multilayer Forest Assemblies", Journal of the American Chemical Society, August 28, 2001, Vol. 123, 9451-9452
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	First Named Inventor	Brent M. Segal et al.
	Art Unit	1775
	Examiner Name	TBA
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